# NSN 5961-00-730-1406

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.450 inches

## **Overall Diameter:**

0.875 inches

## **Mounting Facility Quantity:**

2

### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

**Mounting Method:** 

Unthreaded hole

Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Germanium

### Voltage Rating In Volts Per Characteristic:

120.0 breakdown voltage, collector-to-base, emitter open and 5.0 breakdown voltage, emitter-to-base, collector open and 120.0

breakdown voltage, collector-to-emitter, base open

### **Current Rating Per Characteristic:**

10.00 amperes source cutoff current and 5.00 amperes source cutoff current

#### Power Rating Per Characteristic:

85.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius case

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Terminal Type And Quantity:**

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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